ANALOG DEVICES

HMC784MS8GE

v00.0808

GaAs MMIC 10 WATT T/R SWITCH
DC - 4 GHz

RoHS ✓
EARTH FRIENDLY

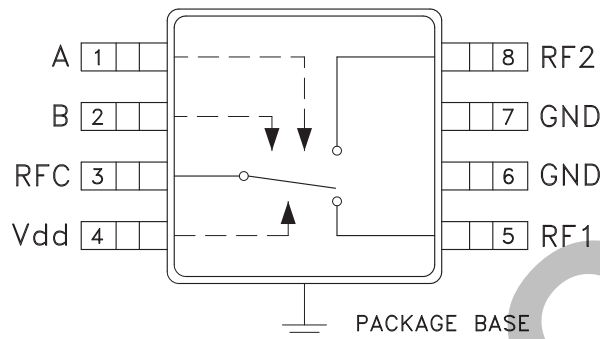SWITCHES - SPDT - SMT

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Typical Applications

The HMC784MS8GE is ideal for:

• Cellular / 4G Infrastructure

• WiMAX, WiBro & Fixed Wireless

• Automotive Telematics

• Mobile Radio

• Test Equipment

Functional Diagram

PACKAGE BASE

Features

Input P1dB: +40 dBm @ Vdd = +8V

High Third Order Intercept: +62 dBm

Positive Control: +3 to +8 V

Low Insertion Loss: 0.4 dB

MSOP8G Package: 14.8 mm²

General Description

The HMC784MS8GE is a high power SPDT switch in an 8-lead MSOPG package for use in transmit-receive applications which require very low distortion at high input signal power levels. The device can control signals from DC to 4 GHz. The design provides exceptional intermodulation performance; > +60 dBm third order intercept at +5V bias. RF1 and RF2 are reflective shorts when "OFF". On-chip circuitry allows single positive supply operation from +3 Vdc to +8 Vdc at very low DC current with control inputs compatible with CMOS and most TTL logic families.

Electrical Specifications,
T$_A$ = +25° C, Vctl = 0/Vdd, Vdd = +5V (Unless Otherwise Stated), 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz DC - 4.0 GHz		0.4 0.6 0.8 0.9 1.3	0.6 0.8 1.1 1.3 2.0	dB dB dB dB dB
Isolation	DC - 4.0 GHz	26	30		dB
Return Loss (On State)	DC - 1.0 GHz DC - 2.0 GHz DC - 3.0 GHz DC - 4.0 GHz		35 30 20 10		dB dB dB dB
Input Power for 0.1dB Compression	Vdd = +3V Vdd = +5V Vdd = +8V	0.1 - 4.0 GHz		32 37 38		dBm dBm dBm
Input Power for 1dB Compression	Vdd = +3V Vdd = +5V Vdd = +8V	0.1 - 4.0 GHz	32 35 38	35 38 41		dBm dBm dBm
Input Third Order Intercept (Two-tone input power = +30 dBm each tone)	0.02 - 0.1 GHz 0.1 - 2.0 GHz 0.1 - 3.0 GHz 0.1 - 4.0 GHz		42 62 61 60		dBm dBm dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	DC - 4.0 GHz		15 40		ns ns

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Phone: 781-329-4700 • Order online at www.analog.com
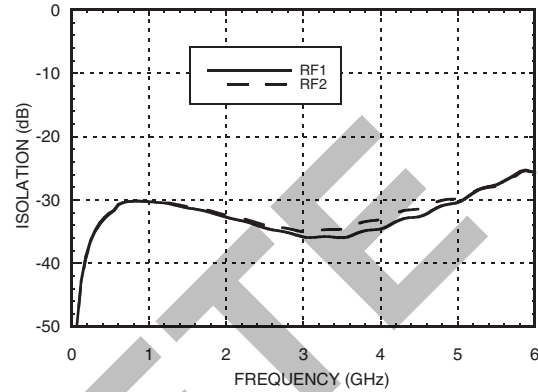Application Support: Phone: 1-800-ANALOG-D

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GaAs MMIC 10 WATT T/R SWITCH
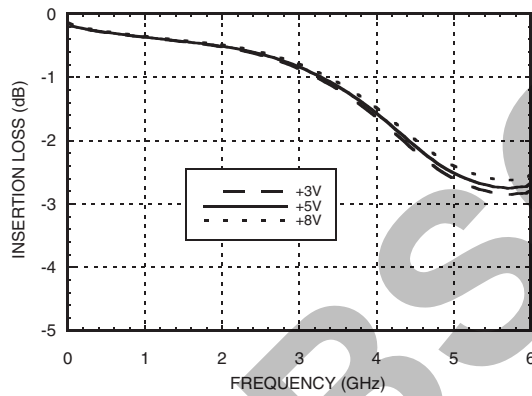## DC - 4 GHz

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EARTH FRIENDLY

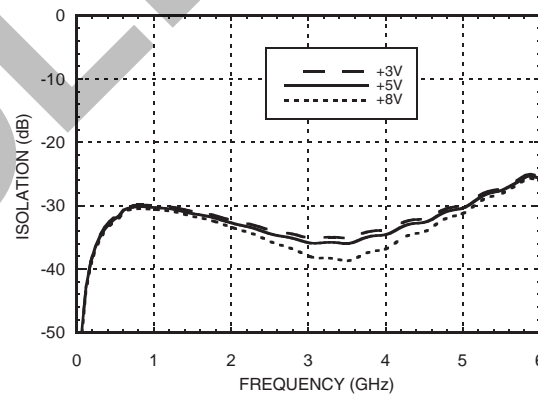### Insertion Loss vs. Temperature
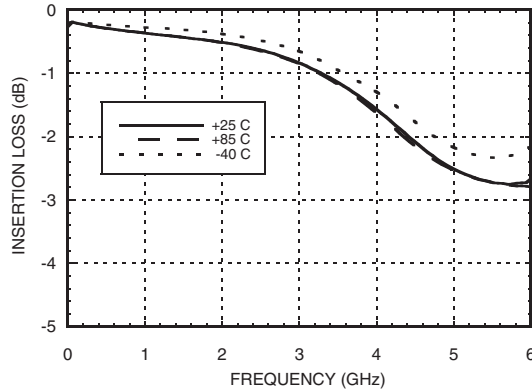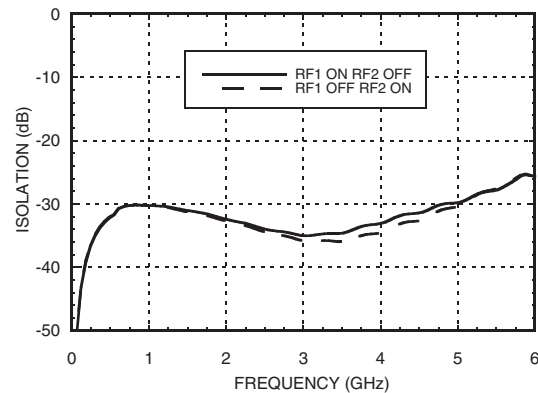

Isolation

Insertion Loss vs. Vdd

Isolation vs. Vdd

Return Loss

RF1 to RF2 Isolation

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OBSOLETE

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Input P1dB vs. Vdd

Input P0.1dB vs. Vdd

Input P1dB vs. Temperature @ Vdd = +5V

Input IP3 vs. Tone Power @ Vdd = +3V

Input IP3 vs. Tone Power @ Vdd = +5V

Input IP3 vs. Tone Power @ Vdd = +8V

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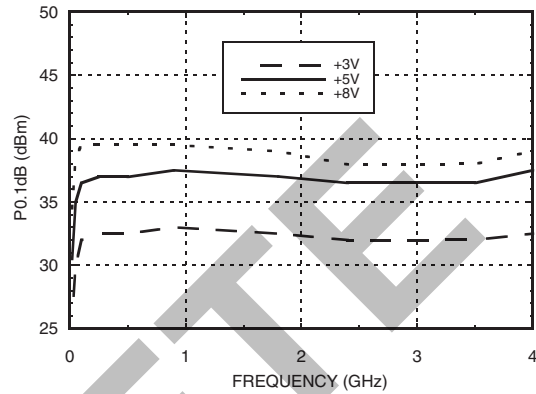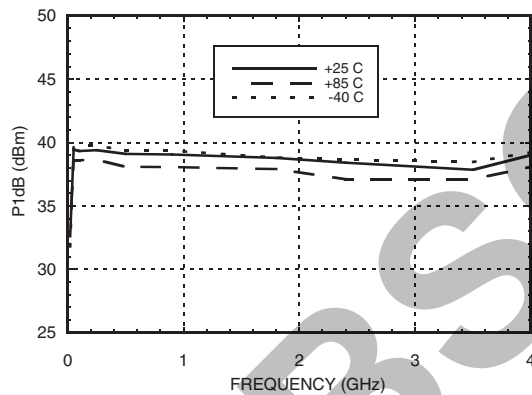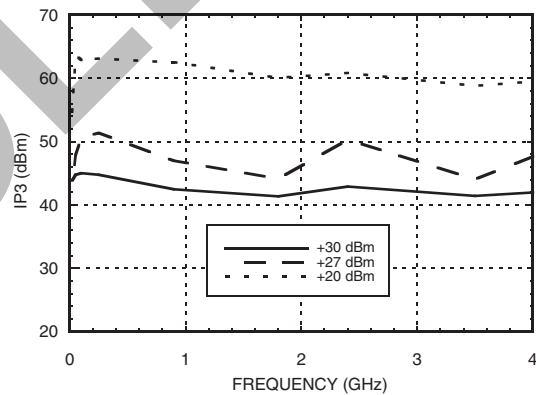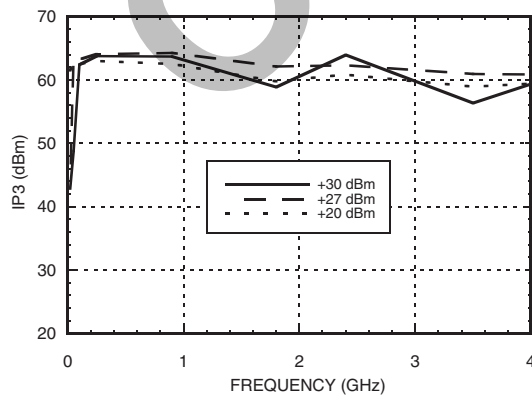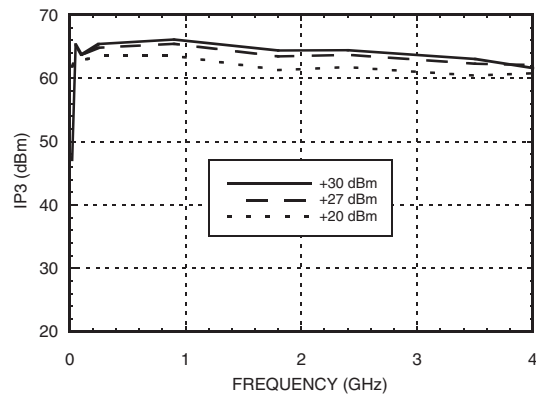
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Input IP3 vs. Temperature
27 dBm Tones, Vdd = +3V

Input IP3 vs. Temperature
27 dBm Tones, Vdd = +5V
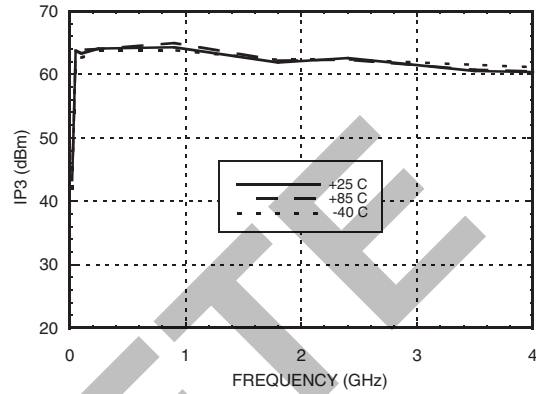
Input IP3 vs. Temperature
27 dBm Tones, Vdd = +8V

Input P1dB vs. Vdd
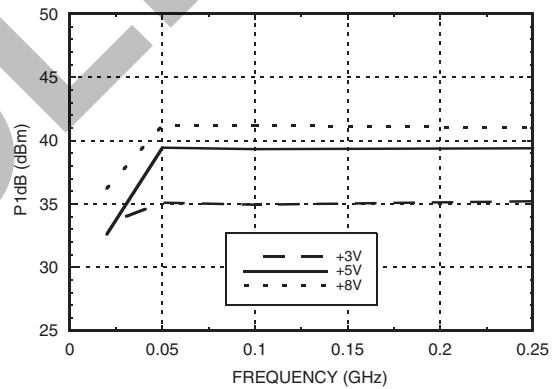
Input P0.1dB vs. Vdd

Input IP3 vs. Tone Power @ Vdd = +5V

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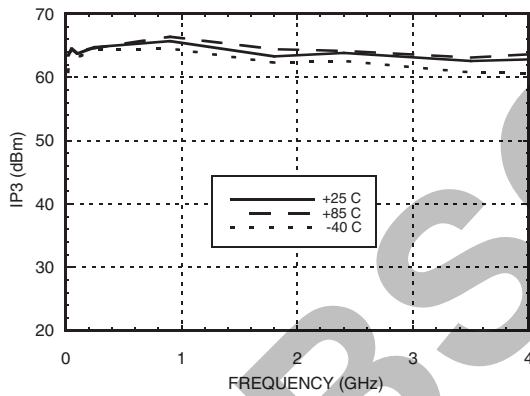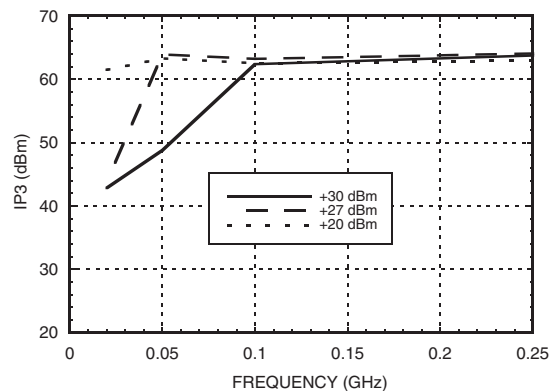*DC - 4 GHz*

Bias Voltage & Current

Vdd (V)	Typical Idd (µA)
+3	0.5
+5	2
+8	20

Control Voltages & Currents

State	Vdd = +3V (µA)	Vdd = +5V (µA)	Vdd = +8V (µA)
Low (0 to +0.2V)	0.5	2	20
High (Vdd ±0.2V)	0.1	0.1	0.1

Truth Table

Control Input (Vctl)		Signal Path State	
A	B	RFC to RF1	RFC to RF2
High	Low	Off	On
Low	High	On	Off

Absolute Maximum Ratings

RF Input Power (Vdd = +8V, 50 Ohm source & load impedances)	+39 dBm (T = +85 °C)
Supply Voltage Range (Vdd) (Vctl = 0V)	-0.2 to +9V
Control Voltage Range (A & B)	-0.2 to Vdd +0.5V
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 25 mW/°C above 85 °C)	1.217 W
Thermal Resistance (Channel to ground paddle)	53.4 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Rating	Class 1A HBM

Note: DC blocking capacitors are required at ports RFC, RF1 and RF2. Their value will determine the lowest transmission frequency.

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

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Outline Drawing
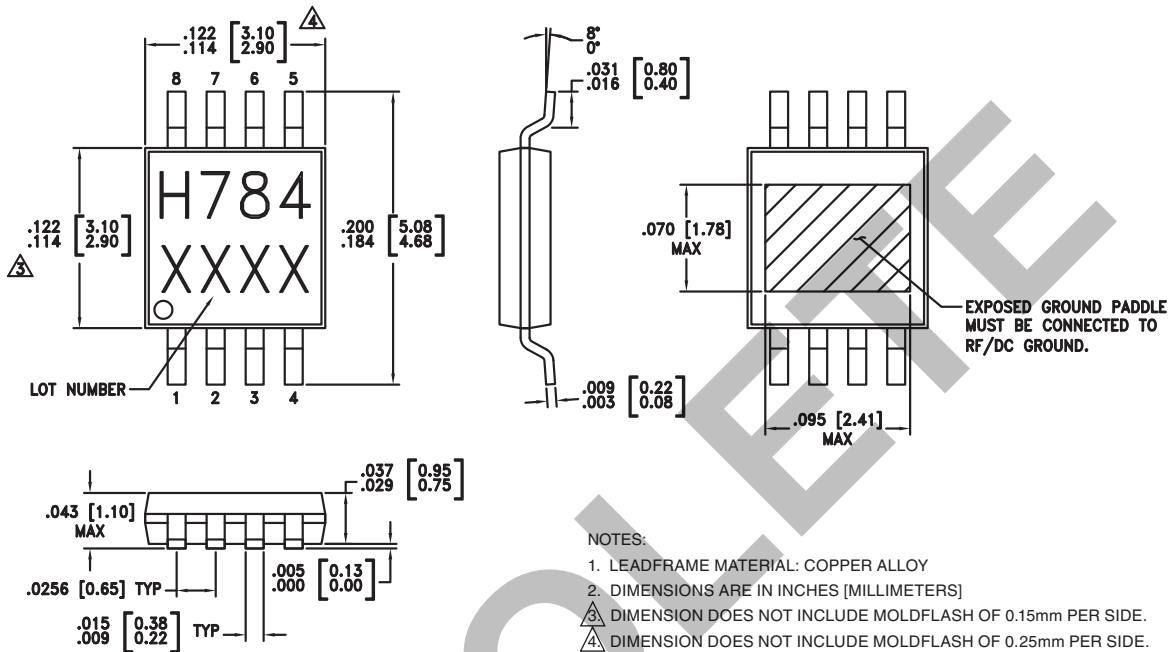
NOTES:
1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

EXPOSED GROUND PADDLE MUST BE CONNECTED TO RF/DC GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [1]
HMC784MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H784 XXXX

[1] 4-Digit lot number XXXX
[2] Max peak reflow temperature of 260 °C

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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	A	See truth table and control voltage table.	A,B —[R]— C
2	B	See truth table and control voltage table.	
3, 5, 8	RFC, RF1, RF2	This pin is DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
4	Vdd	Supply Voltage	
6, 7	GND	Package bottom must also be connected to PCB RF ground.	GND

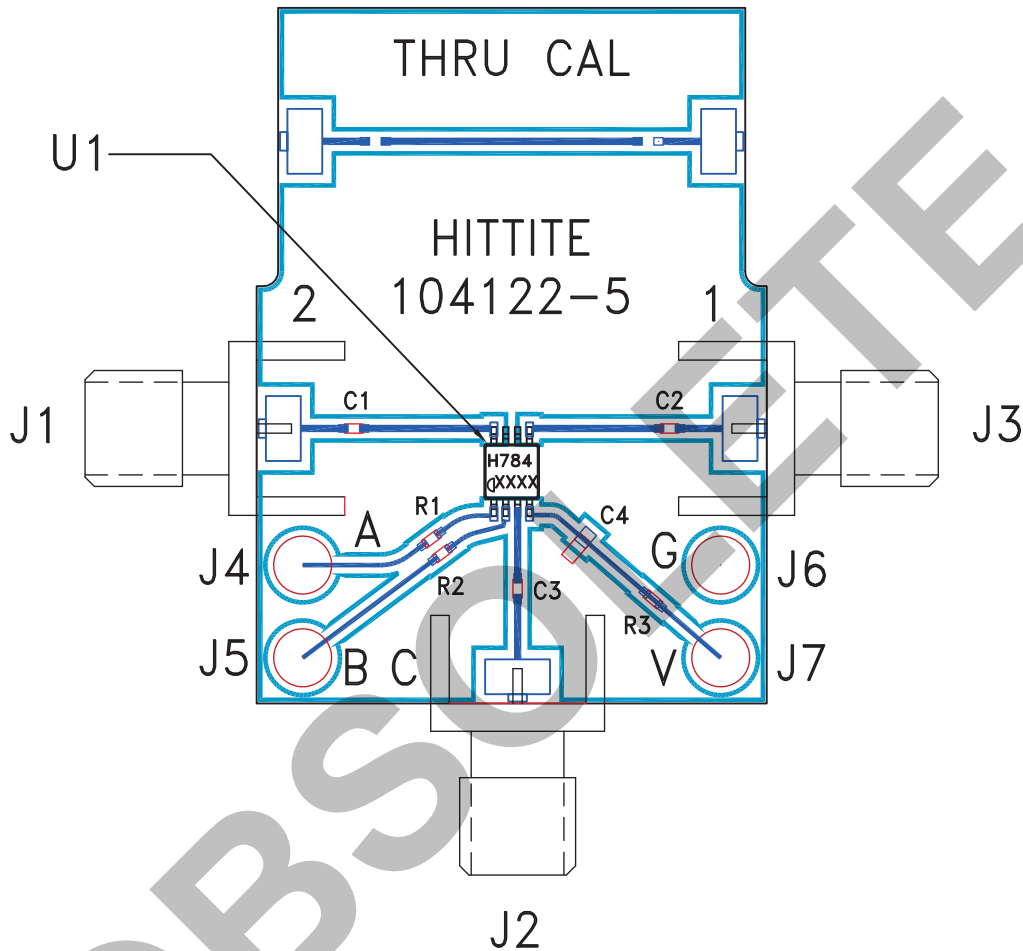## Typical Application Circuit
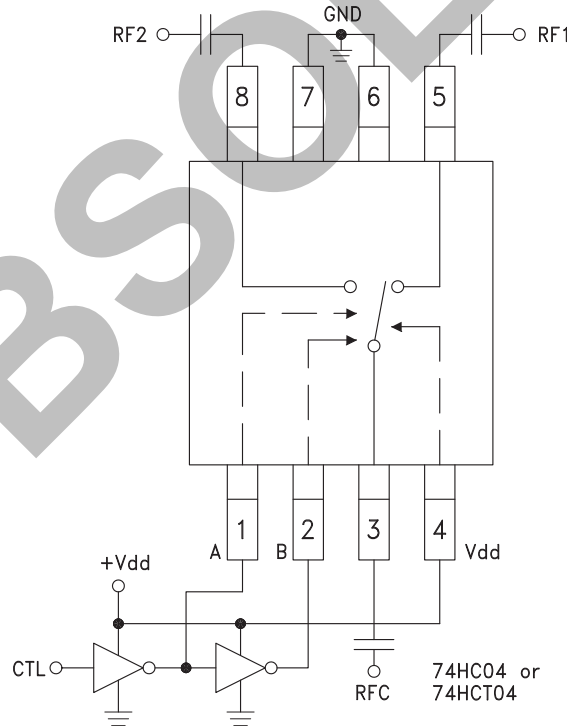
Notes:

1. Set logic gate and switch Vdd = +3V to +8V and use HCT series logic to provide a TTL driver interface.
2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of +3 to +8 Volts applied to the CMOS logic gates and to pin 4 of the RF switch.
3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
4. Highest RF signal power capability is achieved with V set to +8V. The switch will operate properly (but at lower RF power capability) at bias voltages down to +3V.

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Evaluation Circuit Board

List of Materials for Evaluation PCB 104124 [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J7	DC Pin
C1 - C3	100 pF capacitor, 0402 Pkg.
C4	10 KpF capacitor, 0603 Pkg.
R1 - R3	100 Ohm Resistor, 0402 Pkg.
U1	HMC784MS8GE T/R Switch
PCB [2]	104122 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

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